



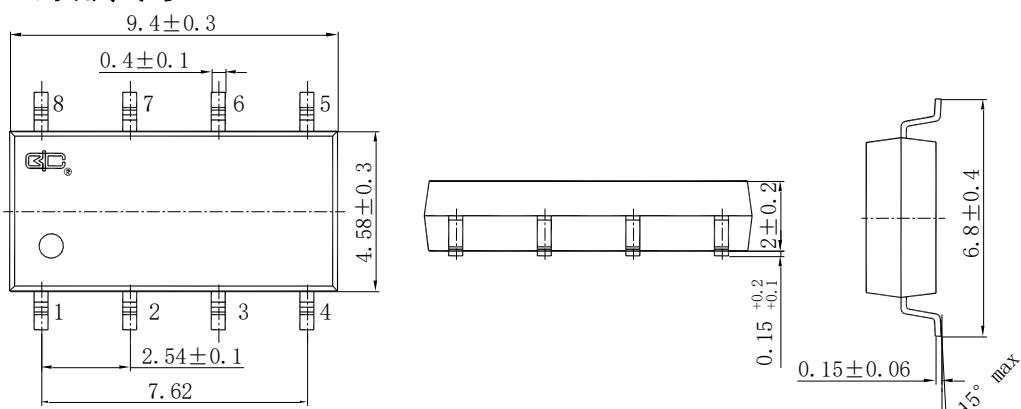
BCW211G1S 型光 MOS 继电器

产品图片	Features 产品特性	Application 应用
 SOP8	<ul style="list-style-type: none"> ● Contact Form 触点形式 2a ● Load Voltage 输出电压 40V ● Load Current 输出电流 3.5A ● Low Off-State Leakage Current 漏电流 0.1μA 	<ul style="list-style-type: none"> ● Electric Vehicle 新能源电动汽车 ● Automatic Test Equipment 自动检测设备 ● Security Equipment 安全设备 ● Sensing Equipment 传感设备 ● Telephone Equipment 通信设备 ● I/O Modules I/O 模块 ● Modem 调制解调器

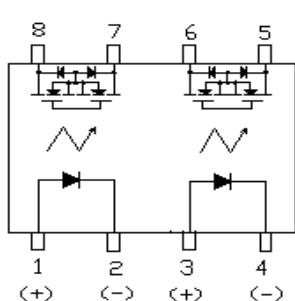
Type 种类

Output rating 输出额定		Marking model 标刻型号	Part No. 订货型号
Load voltage 负载电压	Load current 负载电流		
40V	3.5A	BCW211G1S	BCW211G1S

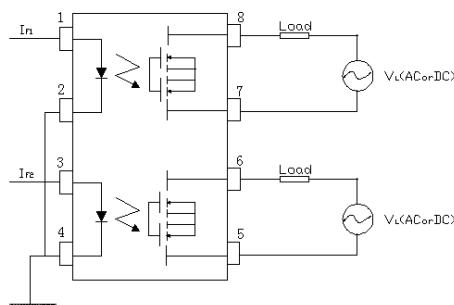
Dimensions 外形尺寸



Terminal Identification 引脚标识



Wiring Diagram 接线图



通讯地址：陕西省西安市国家民用航天产业基地航天中路385号众创广场11层1101、1102、1104室

生产地址：陕西省宝鸡市陈仓区群力路1号邮政编码：721300

电话：(0917)-6293969 (0917)-6293785

传真：(0917)-6293969



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Technical parameters 技术参数 (Ambient Temperature 25°C)

I/O Absolute Maximum Ratings 输入输出电气参数最大值

Item 项目		Symbol 符号	Value 数值
Operating Temperature 工作温度		T _{OPR}	-40°C~+85°C
Storage Temperature 储存温度		T _{STG}	-40°C~100°C
Input 输入	Continuous LED Current 工作电流	I _F	50mA
	Peak LED Current LED 峰值电流 (f=100Hz, Duty=1%)	I _{FP}	1000mA
	LED Reverse Voltage 反向电压	V _R	5V
	Input Power Dissipation 输入功耗	P _{IN}	75mW
Output 输出	Load Voltage 输出电压	V _L	40V
	Load Current 输出电流	I _L	3.5A
	Peak Load Current 峰值输出电流 ((300 μs, 1 shot))	I _{PEAK}	5.0A
	Output Power Dissipation 输出功耗	P _{OUT}	400mW
Total Power Dissipation 总功耗		P _T	600mW
I/O Breakdown Voltage 输入输出间隔离电压 (RH=60%, 1min)		V _{I/O}	1500Vrms

Electrical Specifications 输入输出电气参数

Item 项目		Symbol 符号	MIN. 最小值	TYP. 典型值	MAX. 最大值	Units 单位	Conditions 条件
Input 输入	LED Forward Voltage 正向电压	V _F		1.2	1.4	V	I _F =10mA
	Operation LED Current 接通电流	I _{F ON}		0.5	2.0	mA	
	Recovery LED Voltage 关断电压	V _{F OFF}	0.7			V	
Output 输出	On-Resistance 导通电阻	R _{ON}		0.05	0.08	Ω	I _F =5mA, I _L =100mA, within 1sec.
	Off-State Leakage Current 漏电流	I _{LEAK}			0.1	μA	V _L =Rating
	Output Capacitance 输出端容量	C _{OUT}		240		pF	V _L =0V, f=1MHz
Time Parameters 时间参数	Turn-On Time 接通时间	T _{ON}		0.4	0.8	ms	I _F =5mA
	Turn-Off Time 关断时间	T _{OFF}		0.03	0.05	ms	I _L =100mA
I/O 输入输出	I/O Insulation Resistance 绝缘电阻	R _{I/O}	10 ¹⁰			Ω	DC=500V
	I/O Capacitance 隔离电容	C _{I/O}		0.8	1.5	pF	f=1MHz

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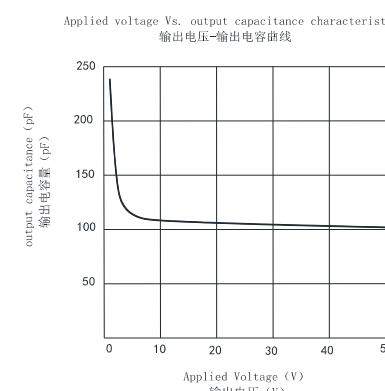
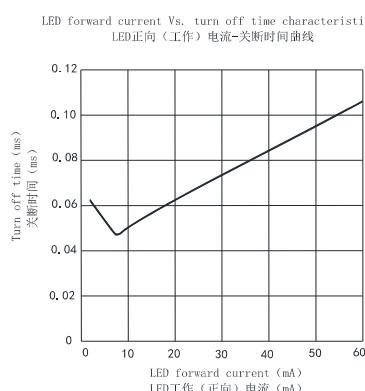
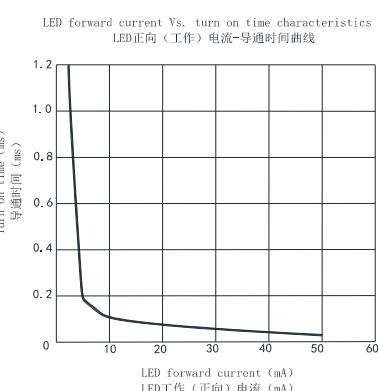
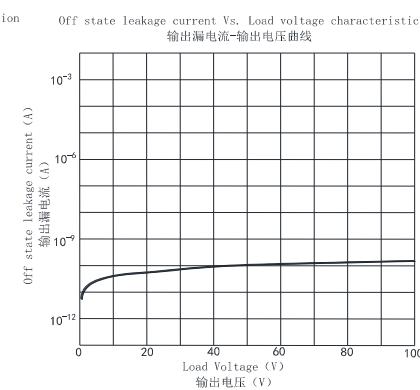
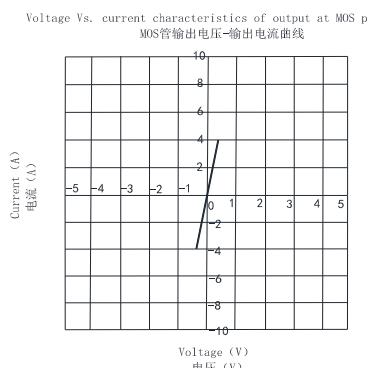
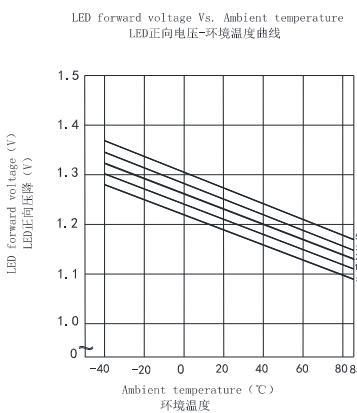
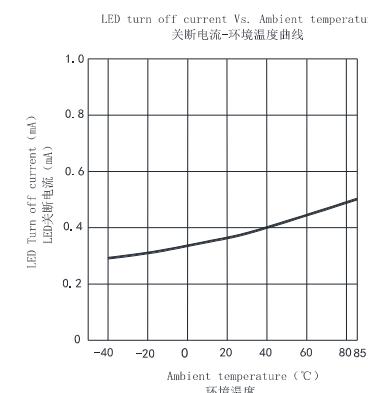
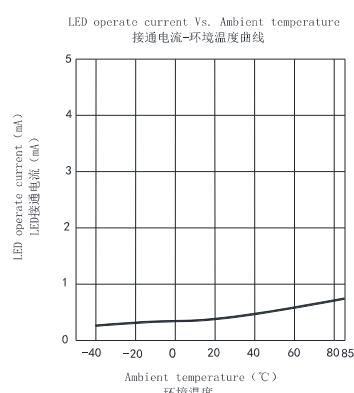
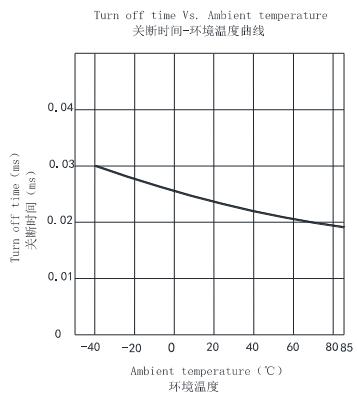
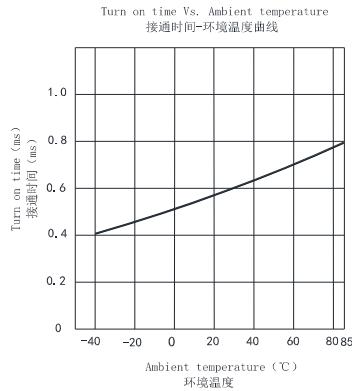
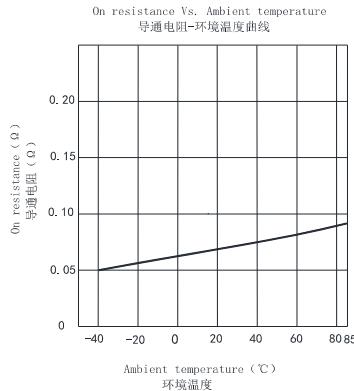
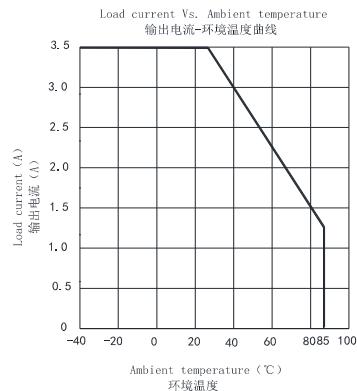
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Reference Data 参考数值 (BCW211G1S)



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